

# Dirac Fermion Reflector as a Scattering Length Meter

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Electron propagation in ballistic graphene bears strong analogies with optics, with the Fermi energy as the optical index and p-n junctions acting as dioptrics [1,2]. Using nano-patterned bottom gates (Fig. 1) and h-BN encapsulated graphene, we create a prism-shaped doping profile acting as a Dirac fermion (DF) reflector.

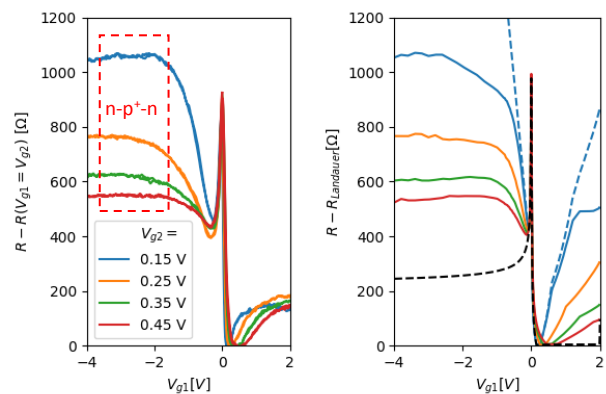
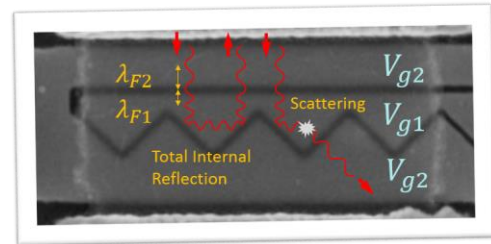
We demonstrate the reflection effect and the full tunability of the DF optical index in agreement with a scattering model (Fig. 1). The DF-reflector operates at large negative gate voltage ( $V_{g1}$ ) where the DFR resistance saturates according to the finite scattering length.

The DFR device is a sensitive meter of scattering length in the range 0.6-6  $\mu\text{m}$ . It is used in Fig. 2 to measure the phonon scattering length in good agreement with theory.

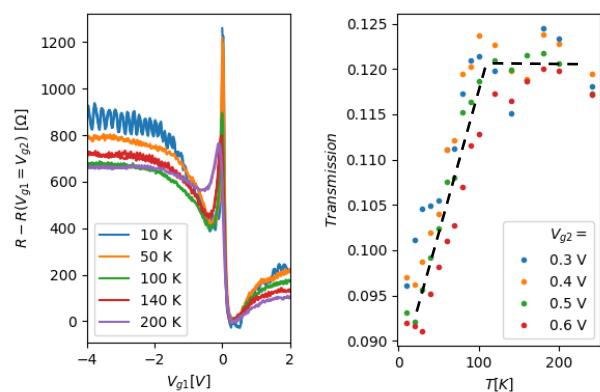
## References

- [1] Wilmart, Berada et al., 2D Mat., 1 (2014) 011006
- [2] Morikawa, Wilmart et al., Semicond. Sci. Technol., 32 (2017) 045010

## Figures



**Figure 1:** Top: Illustration of the Dirac Fermion Reflector. Left: Device resistance as a function of  $V_{g1}$  for various  $V_{g2}$ . The red box indicates the operation regime of the reflector. Right: Simulation taking into account scattering lengths ranging from 0.7 to 2.8  $\mu\text{m}$ . We also show the case of no scattering and of a rectangular gate (blue and black dashed lines, respectively).



**Figure 3:** Left: Characterising the Dirac Fermion Reflector at various temperatures ( $V_{g2}=0.3$  V). At low temperatures, resistance oscillates as a signature of coherent DF optics. As we increase the temperature, we see the plateau resistance decrease, i.e. the residual transmission (right) increases steeply.